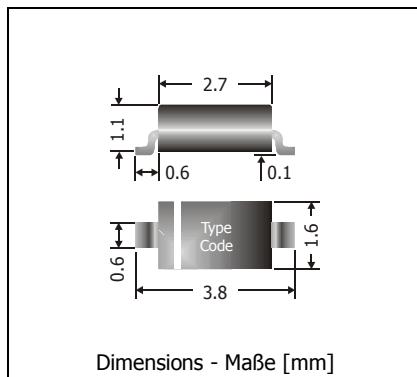


**BAT46W**
**Surface Mount Schottky Barrier Diodes**  
**Schottky-Barrier-Dioden für die Oberflächenmontage**

Version 2009-10-29



|  |         |
|--|---------|
| Power dissipation – Verlustleistung          | 200 mW  |
| Repetitive peak reverse voltage              | 100 V   |
| Periodische Spitzensperrspannung             |         |
| Plastic case – Kunststoffgehäuse             | SOD-123 |
| Weight approx. – Gewicht ca.                 | 0.01 g  |
| Plastic material has UL classification 94V-0 |         |
| Gehäusematerial UL94V-0 klassifiziert        |         |
| Standard packaging taped and reeled          |         |
| Standard Lieferform gegurtet auf Rolle       |         |

**Maximum ratings ( $T_A = 25^\circ\text{C}$ )****Grenzwerte ( $T_A = 25^\circ\text{C}$ )**

| <b>BAT46W</b>  |  |                              |
|--|--|------------------------------|
| Power dissipation – Verlustleistung  | $P_{\text{tot}}$                             | 200 mW <sup>1)</sup>         |
| Max. average forward current – Dauergrenzstrom (dc)                                      | $I_{\text{FAV}}$                             | 150 mA <sup>1)</sup>         |
| Repetitive peak forward current – Periodischer Spitzenstrom                              | $I_{\text{FRM}}$                             | 350 mA <sup>1)</sup>         |
| Non repetitive peak forward surge current<br>Stoßstrom-Grenzwert                         | $I_{\text{FSM}}$<br>$t_p \leq 10 \text{ ms}$ | 750 mA                       |
| Repetitive peak reverse voltage – Periodische Spitzensperrspannung                       | $V_{\text{RRM}}$                             | 100 V                        |
| Junction temperature – Sperrsichttemperatur<br>Storage temperature – Lagerungstemperatur | $T_j$<br>$T_s$                               | -55...+125°C<br>-55...+150°C |

**Characteristics ( $T_j = 25^\circ\text{C}$ )****Kennwerte ( $T_j = 25^\circ\text{C}$ )**

|   |   |                                  |  |
|---|---|----------------------------------|--|
| Forward voltage<br>Durchlass-Spannung   | $I_F = 0.1 \text{ mA}$<br>$I_F = 10 \text{ mA}$<br>$I_F = 250 \text{ mA}$   | $V_F$<br>$V_F$<br>$V_F$          | < 0.25 V<br>< 0.45 V<br>< 1 V  |
| Leakage current – Sperrstrom <sup>2)</sup>  | $V_R = 1.5 \text{ V}$<br>$V_R = 10 \text{ V}$<br>$V_R = 50 \text{ V}$<br>$V_R = 75 \text{ V}$                             | $I_R$<br>$I_R$<br>$I_R$<br>$I_R$ | < 0.5 $\mu\text{A}$<br>< 0.8 $\mu\text{A}$<br>< 2 $\mu\text{A}$<br>< 5 $\mu\text{A}$ |
| Leakage current – Sperrstrom <sup>2)</sup>  | $T_j = 60^\circ\text{C}$<br>$V_R = 1.5 \text{ V}$<br>$V_R = 10 \text{ V}$<br>$V_R = 50 \text{ V}$<br>$V_R = 75 \text{ V}$ | $I_R$<br>$I_R$<br>$I_R$<br>$I_R$ | < 5 $\mu\text{A}$<br>< 7.5 $\mu\text{A}$<br>< 15 $\mu\text{A}$<br>< 20 $\mu\text{A}$ |
| Total capacitance<br>Gesamtkapazität  | $f = 1 \text{ MHz}$<br>$V_R = 0 \text{ V}$<br>$V_R = 1 \text{ V}$   | $C_T$<br>$C_T$                   | typ. 20 pF<br>typ. 12 pF   |
| Thermal resistance junction to ambient air<br>Wärmewiderstand Sperrsicht – umgebende Luft |   | $R_{\text{thA}}$                 | < 420 K/W <sup>1)</sup>  |

1 Mounted on P.C. board with 3 mm<sup>2</sup> copper pad at each terminal  
Montage auf Leiterplatte mit 3 mm<sup>2</sup> Kupferbelag (Lötpad) an jedem Anschluss

2 Tested with pulses  $t_p = 300 \mu\text{s}$ , duty cycle  $\leq 2\%$  – Gemessen mit Impulsen  $t_p = 300 \mu\text{s}$ , Schaltverhältnis  $\leq 2\%$

Marking – Stempelung

BAT46W = XH

